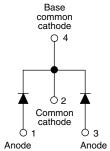


**HALOGEN** 

FREE

## Ultrafast Rectifier, 2 x 3 A FRED Pt®





	Base ommon athode	
	Q 4	
	•	_
+		$\perp$
<b>A</b>	02	<b>A</b>
	ommon	
С	athode	
Ó 1		<b>О</b> 3
Anode		Anode

PRODUCT SUMMARY						
Package	TO-252AA (D-PAK)					
I <sub>F(AV)</sub>	2 x 3 A					
$V_{R}$	200 V					
V <sub>F</sub> at I <sub>F</sub>	0.96 V					
t <sub>rr</sub> typ.	See Recovery table					
T <sub>J</sub> max.	175 °C					
Diode variation	Common cathode					

#### **FEATURES**

- Ultrafast recovery time
- · Low forward voltage drop
- · Low leakage current
- 175 °C operating junction temperature
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **DESCRIPTION / APPLICATIONS**

VS-MURD620CTHM3 is the state of the art ultrafast recovery rectifier specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS				
Peak repetitive reverse voltage	$V_{RRM}$		200	V				
Average rectified forward current per device	I <sub>F(AV)</sub>	Total device, rated V <sub>R</sub> , T <sub>C</sub> = 146 °C	6					
Non-repetitive peak surge current	I <sub>FSM</sub>		50	Α				
Peak repetitive forward current per diode	I <sub>FM</sub>	Rated V <sub>R</sub> , square wave, 20 kHz, T <sub>C</sub> = 146 °C	6					
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C				

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 100 μΑ	200	-	-		
	V <sub>F</sub>	I <sub>F</sub> = 3 A	-	-	1.0	V	
Forward voltage		I <sub>F</sub> = 3 A, T <sub>J</sub> = 125 °C	-	-	0.96	V	
Forward voitage		I <sub>F</sub> = 6 A	-	-	1.2		
		I <sub>F</sub> = 6 A, T <sub>J</sub> = 125 °C	-	-	1.13		
Poverse leekage ourrent	I <sub>R</sub>	$V_R = V_R$ rated	-	-	5		
Reverse leakage current		$T_J = 125  ^{\circ}\text{C},  V_R = V_R  \text{rated}$	-	-	250	μΑ	
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 200 V	-	12	-	pF	
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nΗ	





<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
	t <sub>rr</sub>	$I_F = 1.0 A$ , $dI_F/dt =$	$I_F = 1.0 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		20	35		
Reverse recovery time		T <sub>J</sub> = 25 °C	I <sub>F</sub> = 3 A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 160 V	-	19	-	ns	
		T <sub>J</sub> = 125 °C		-	26	-		
Dools woods on a surrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	3.1	-	Α	
Peak recovery current		T <sub>J</sub> = 125 °C		- 4.6	-	A		
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		=	30	-	0	
		T <sub>J</sub> = 125 °C		=	60	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C	
Thermal resistance, junction to case per leg	R <sub>thJC</sub>		-	-	9.0		
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>		-	-	80	°C/W	
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	-	-		
Woight			-	0.3	-	g	
Weight			-	0.01	-	oz.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Marking device		Case style TO-252AA (D-PAK)	MURD620CTH				

#### www.vishay.com

### Vishay Semiconductors

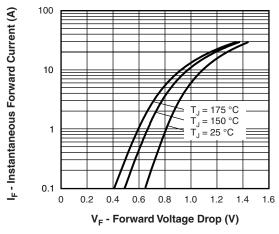


Fig. 1 - Typical Forward Voltage Drop Characteristics

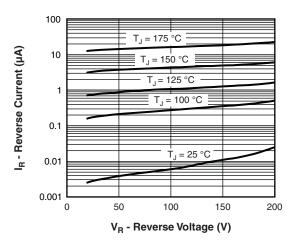


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

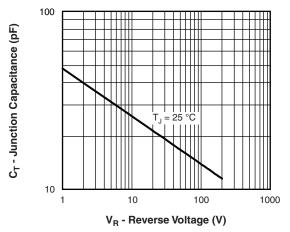


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

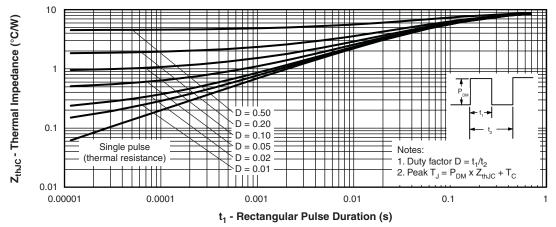


Fig. 4 - Maximum Thermal Impedance  $Z_{\text{thJC}}$  Characteristics





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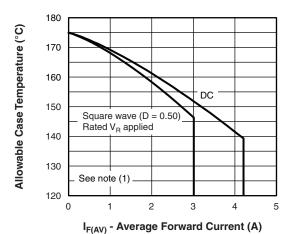


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

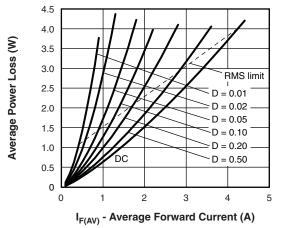


Fig. 6 - Forward Power Loss Characteristics

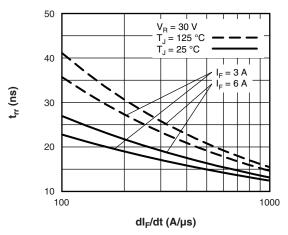


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

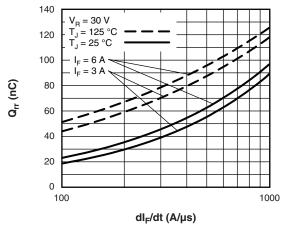


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

### Note

 $\begin{array}{ll} \text{(1)} \ \ \text{Formula used:} \ T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \ \text{at } (I_{F(AV)}/D) \ \text{(see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \ \text{(1 - D)}; \ I_R \ \text{at } V_{R1} = \text{Rated } V_R \\ \end{array}$ 

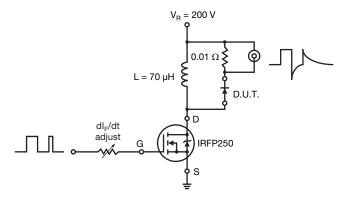
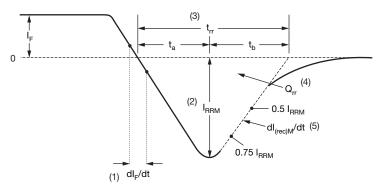


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dI<sub>F</sub>/dt rate of change of current through zero crossing
- (2) I<sub>RRM</sub> peak reverse recovery current
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm I_F$  to point where a line passing through 0.75  $\rm I_{RRM}$  and 0.50  $\rm I_{RRM}$  extrapolated to zero current.
- (4)  $\mathbf{Q}_{rr}$  area under curve defined by  $\mathbf{t}_{rr}$  and  $\mathbf{I}_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

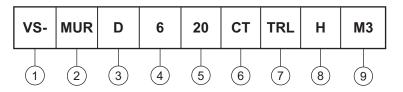
(5)  $dI_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

Fig. 10 - Reverse Recovery Waveform and Definitions



#### **ORDERING INFORMATION TABLE**

Device code



Vishay Semiconductors product

Ultrafast MUR series

D = D-PAK

4 Current rating (6 = 6 A)

Voltage rating (20 = 200 V)

CT = center tap (dual) TR = tape and reel

6 7 8 TRL = tape and reel (left oriented) Tape and reel suffix -TRR = tape and reel (right oriented)

H = AEC-Q101 qualified

Environmental digit:

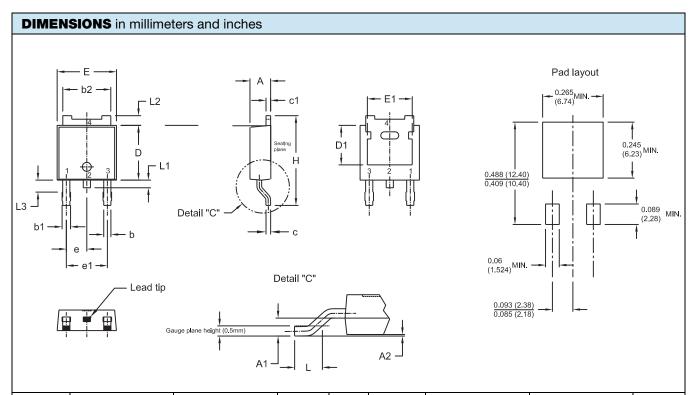
M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-MURD620CTHM3	75	3000	Antistatic plastic tube					
VS-MURD620CTTRHM3	2000	2000	13" diameter reel					
VS-MURD620CTTRLHM3	3000	3000	13" diameter reel					
VS-MURD620CTTRRHM3	3000	3000	13" diameter reel					

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95519</u>					
Part marking information <u>www.vishay.com/doc?95518</u>					
Packaging information	www.vishay.com/doc?95033				



# **D-PAK (TO-252AA)**



SYMBOL	MILLIM	IETERS	INCHES		RS INCHES		NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES		
Α	2.21	2.38	0.087	0.094			
A2	0.03	0.127	0.001	0.005			
b	0.71	0.88	0.028	0.035			
b1	0.76	1.14	0.030	0.045			
b2	5.23	5.44	0.206	0.214			
С	0.46	0.58	0.018	0.023			
C1	0.46	0.58	0.018	0.023			
D	5.97	6.22	0.235	0.2455			
D1	4.32	4.45	0.170	0.175			
Е	6.48	6.73	0.255	0.2655			
E1	4.49	5.50	0.177	0.217			

SYMBOL	MILLIMETERS		INC	NOTES	
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOIES
A1	0.89	1.14	0.035	0.045	
Н	9.65	10.41	0.380	0.410	
L	1.40	1.78	0.055	0.070	
е	2.28 BSC		0.09 BSC		
e1	4.57	BSC	0.18 BSC		
L1	0.64	1.02	0.025	0.040	
L2	0.89	1.27	0.035	0.050	
L3	1.15	1.52	0.040	0.060	

#### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L3 only for reference
- Dimension D1, E1, L2 and b2 establish a minimum mounting surface for thermal pad
- (4) Dimensions D and E do not include mold flash.
- (5) Outline conforms to JEDEC outline TO-252AA



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